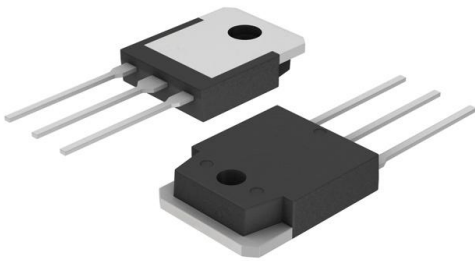


FDA28N50F Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	FDA28N50F-DG
Manufacturer	onsemi
Manufacturer Product Number	FDA28N50F
Description	MOSFET N-CH 500V 28A TO3PN
Detailed Description	N-Channel 500 V 28A (Tc) 310W (Tc) Through Hole TO-3PN

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RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

FDA28N50F

Series:

UniFET™

FET Type:

N-Channel

Drain to Source Voltage (Vdss):

500 V

Drive Voltage (Max Rds On, Min Rds On):

10V

Vgs(th) (Max) @ Id:

5V @ 250µA

Vgs (Max):

±30V

FET Feature:

-

Operating Temperature:

-55°C ~ 150°C (Tj)

Supplier Device Package:

TO-3PN

Base Product Number:

FDA28

Manufacturer:

onsemi

Product Status:

Active

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

28A (Tc)

Rds On (Max) @ Id, Vgs:

175mOhm @ 14A, 10V

Gate Charge (Qg) (Max) @ Vgs:

105 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

5387 pF @ 25 V

Power Dissipation (Max):

310W (Tc)

Mounting Type:

Through Hole

Package / Case:

TO-3P-3, SC-65-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

Not Applicable

ECCN:

EAR99



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FDA28N50F

N-Channel UniFET™ FRFET® MOSFET

500 V, 28 A, 175 mΩ

Features

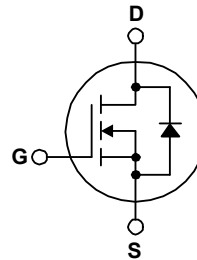
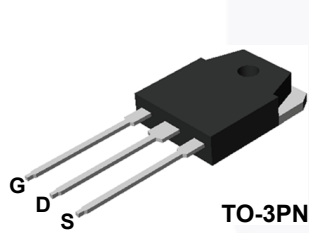
- $R_{DS(on)} = 140\text{ m}\Omega$ (Typ.) @ $V_{GS} = 10\text{ V}$, $I_D = 14\text{ A}$
- Low Gate Charge (Typ. 80 nC)
- Low C_{rss} (Typ. 38 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant

Applications

- PDP TV
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. The body diode's reverse recovery performance of UniFET FRFET® MOSFET has been enhanced by lifetime control. Its trr is less than 100nsec and the reverse dv/dt immunity is 15V/ns while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore, it can remove additional component and improve system reliability in certain applications in which the performance of MOSFET's body diode is significant. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FDA28N50F	Unit
V_{DSS}	Drain to Source Voltage	500	V
V_{GSS}	Gate to Source Voltage	± 30	V
I_D	Drain Current	- Continuous ($T_C = 25^\circ\text{C}$)	28
		- Continuous ($T_C = 100^\circ\text{C}$)	17
I_{DM}	Drain Current	- Pulsed (Note 1)	112
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	2352
I_{AR}	Avalanche Current	(Note 1)	28
E_{AR}	Repetitive Avalanche Energy	(Note 1)	31
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	20
P_D	Power Dissipation	($T_C = 25^\circ\text{C}$)	310
		- Derate Above 25°C	2.5
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds	300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	FDA28N50F	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.4	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	40	

FDA28N50F — N-Channel UniFET™ FRFET® MOSFET

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDA28N50F	FDA28N50F	TO-3PN	Tube	N/A	N/A	30 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}$, $V_{GS} = 0 \text{ V}$, $T_J = 25^\circ\text{C}$	500	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$, Referenced to 25°C	-	0.7	-	$\text{V}/^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 500 \text{ V}$, $V_{GS} = 0 \text{ V}$ $V_{DS} = 400 \text{ V}$, $T_C = 125^\circ\text{C}$	-	-	1 10	μA
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0 \text{ V}$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu\text{A}$	3.0	-	5.0	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}$, $I_D = 14 \text{ A}$	-	0.140	0.175	Ω
g_{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}$, $I_D = 14 \text{ A}$	-	35	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}$, $V_{GS} = 0 \text{ V}$, $f = 1 \text{ MHz}$	-	3975	5387	pF
C_{oss}	Output Capacitance		-	566	753	pF
C_{rss}	Reverse Transfer Capacitance		-	38	56	pF
$Q_{g(tot)}$	Total Gate Charge at 10V	$V_{DS} = 400 \text{ V}$, $I_D = 28 \text{ A}$, $V_{GS} = 10 \text{ V}$	-	80	105	nC
Q_{gs}	Gate to Source Gate Charge		-	22	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	-	31	-

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 250 \text{ V}$, $I_D = 28 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_G = 25 \Omega$	-	67	145	ns
t_r	Turn-On Rise Time		-	137	285	ns
$t_{d(off)}$	Turn-Off Delay Time		-	192	395	ns
t_f	Turn-Off Fall Time		(Note 4)	-	101	212

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain to Source Diode Forward Current	-	-	28	A	
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current	-	-	112	A	
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}$, $I_{SD} = 28 \text{ A}$	-	-	1.5	V
t_{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}$, $I_{SD} = 28 \text{ A}$, $di_F/dt = 100 \text{ A}/\mu\text{s}$	-	266	-	ns
Q_{rr}	Reverse Recovery Charge		-	1.38	-	μC

Notes:

1. Repetitive rating; pulse-width limited by maximum junction temperature.
2. $L = 6 \text{ mH}$, $I_{AS} = 28 \text{ A}$, $V_{DD} = 50 \text{ V}$, $R_G = 25 \Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq 28 \text{ A}$, $di/dt \leq 200 \text{ A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

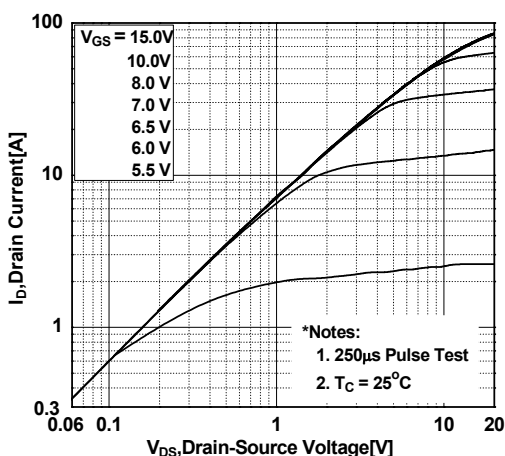


Figure 2. Transfer Characteristics

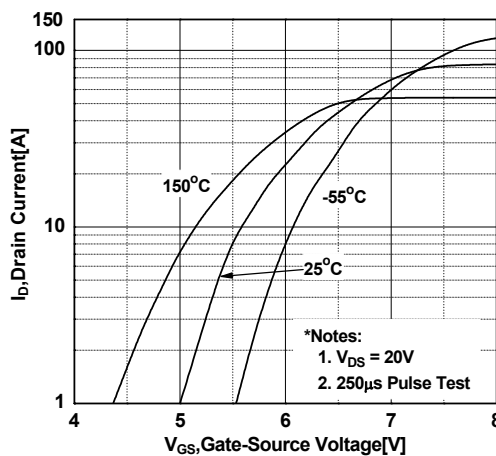


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

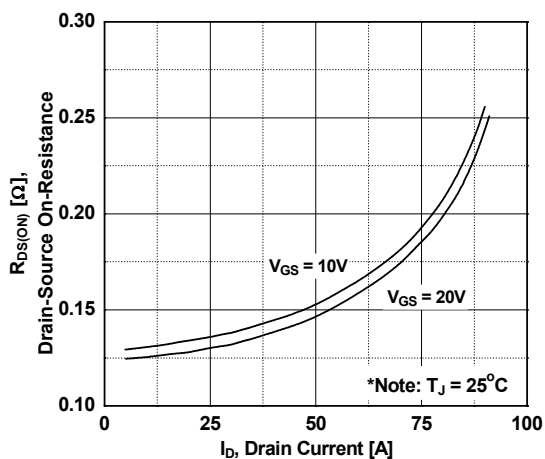


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

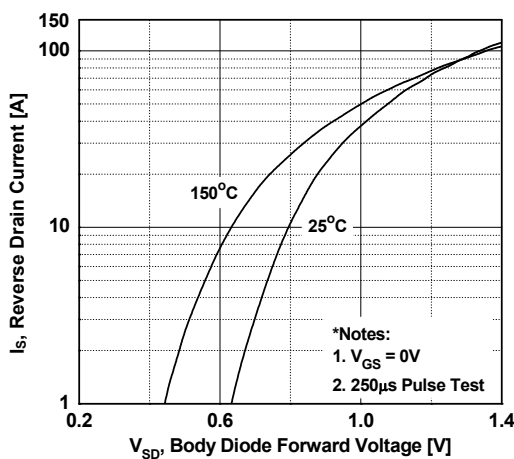


Figure 5. Capacitance Characteristics

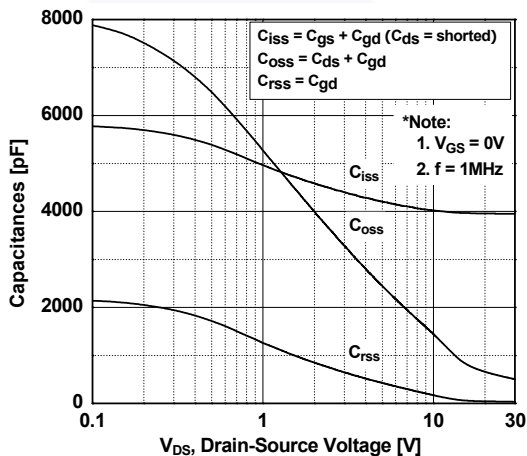
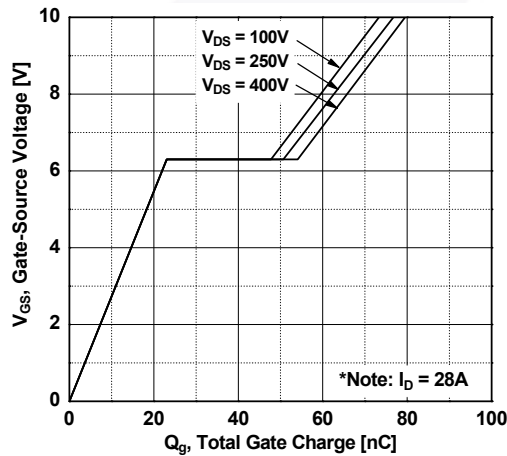


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

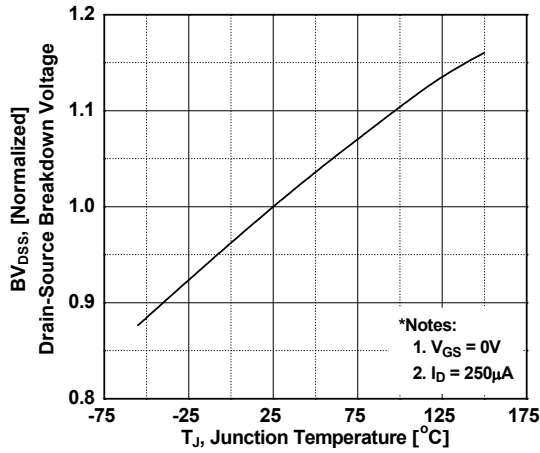


Figure 8. On-Resistance Variation vs. Temperature

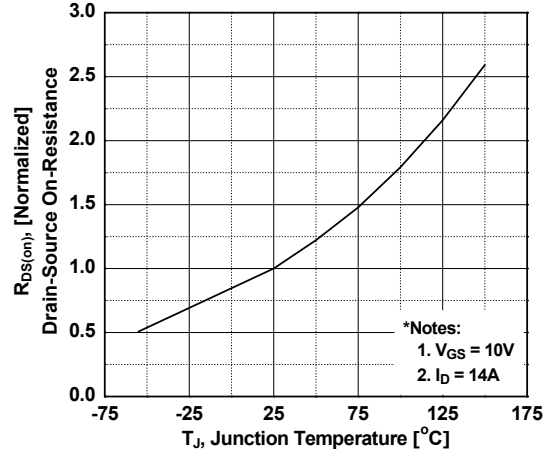


Figure 9. Maximum Safe Operating Area

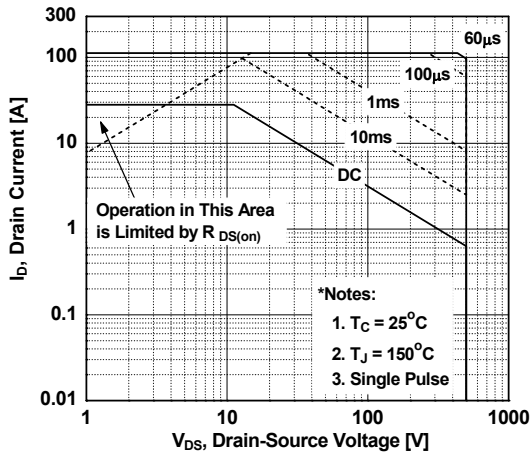


Figure 10. Maximum Drain Current vs. Case Temperature

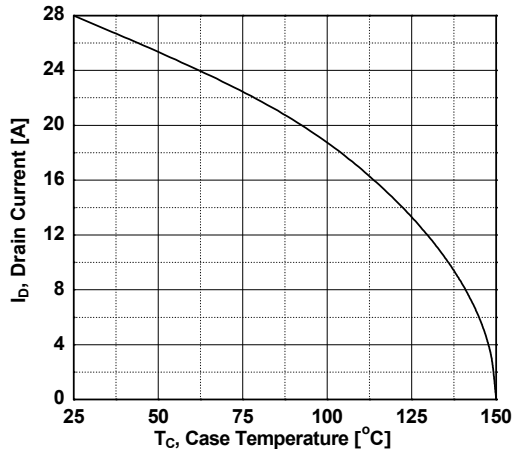
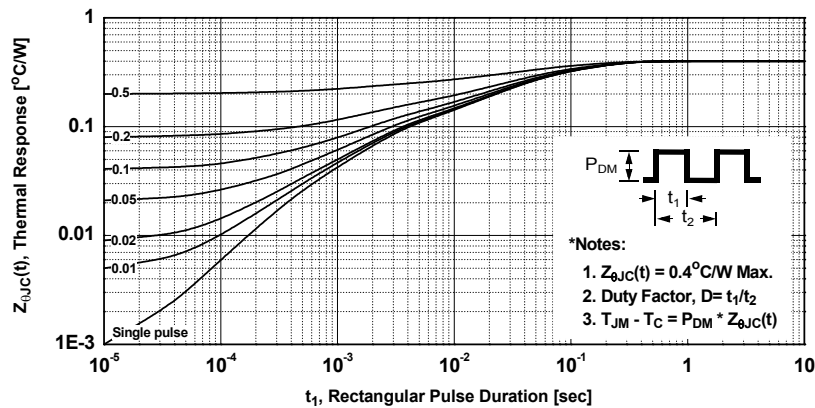


Figure 11. Transient Thermal Response Curve



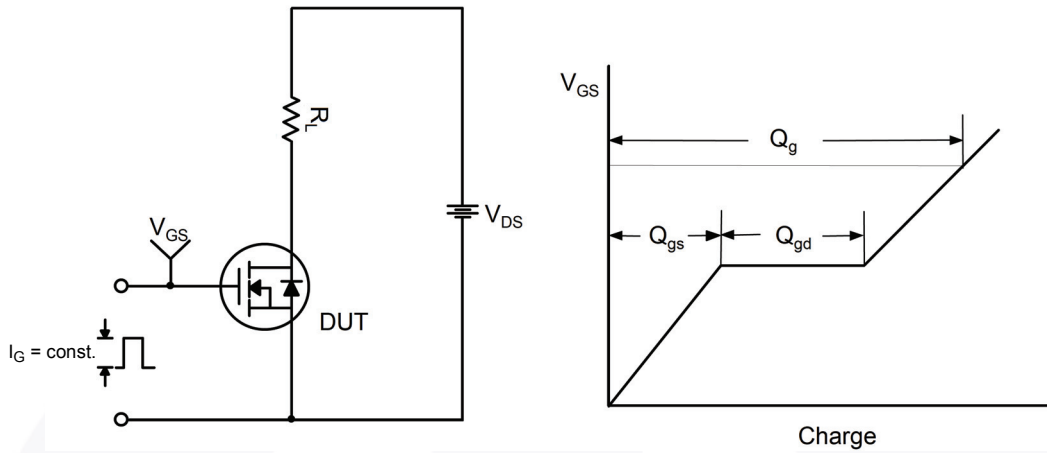


Figure 12. Gate Charge Test Circuit & Waveform

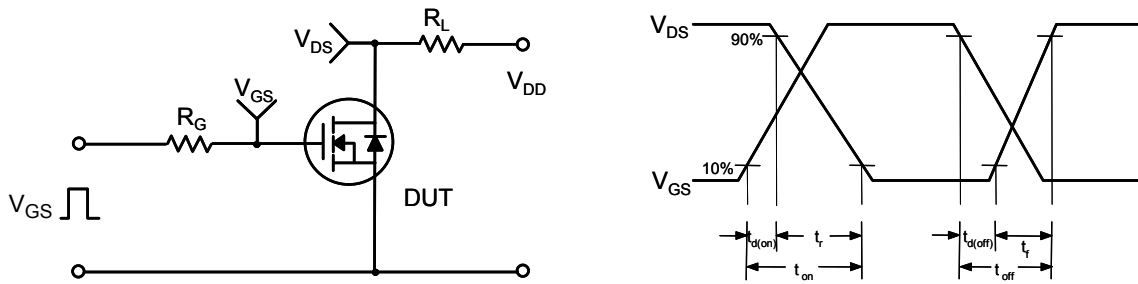


Figure 13. Resistive Switching Test Circuit & Waveforms

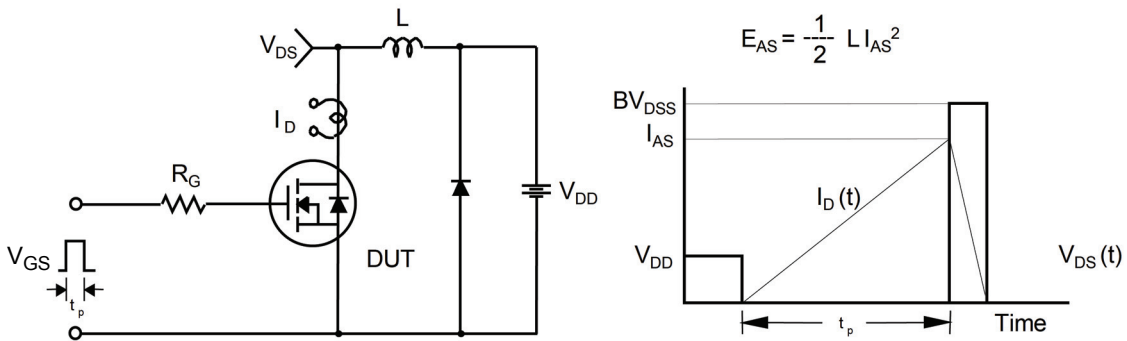


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

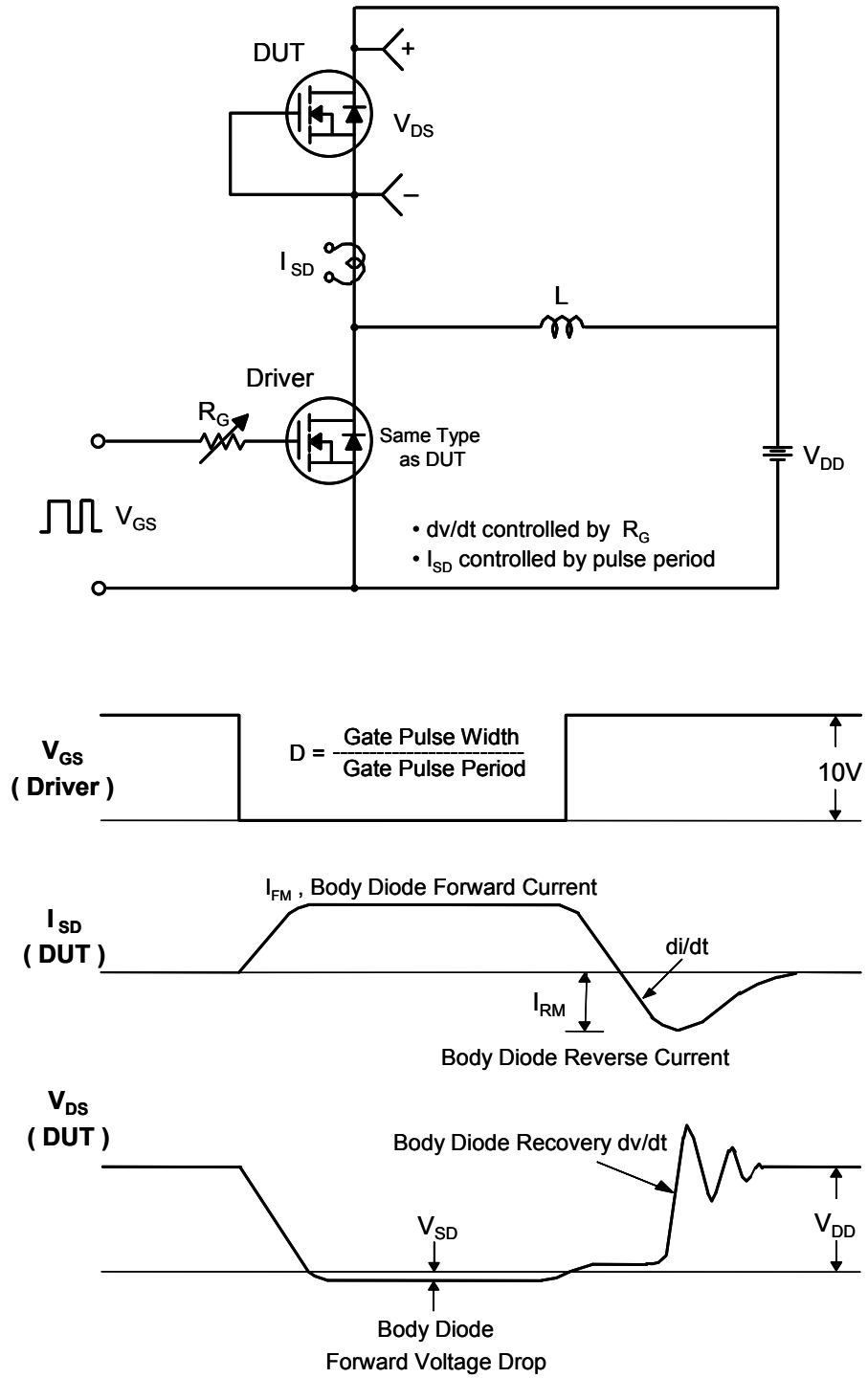
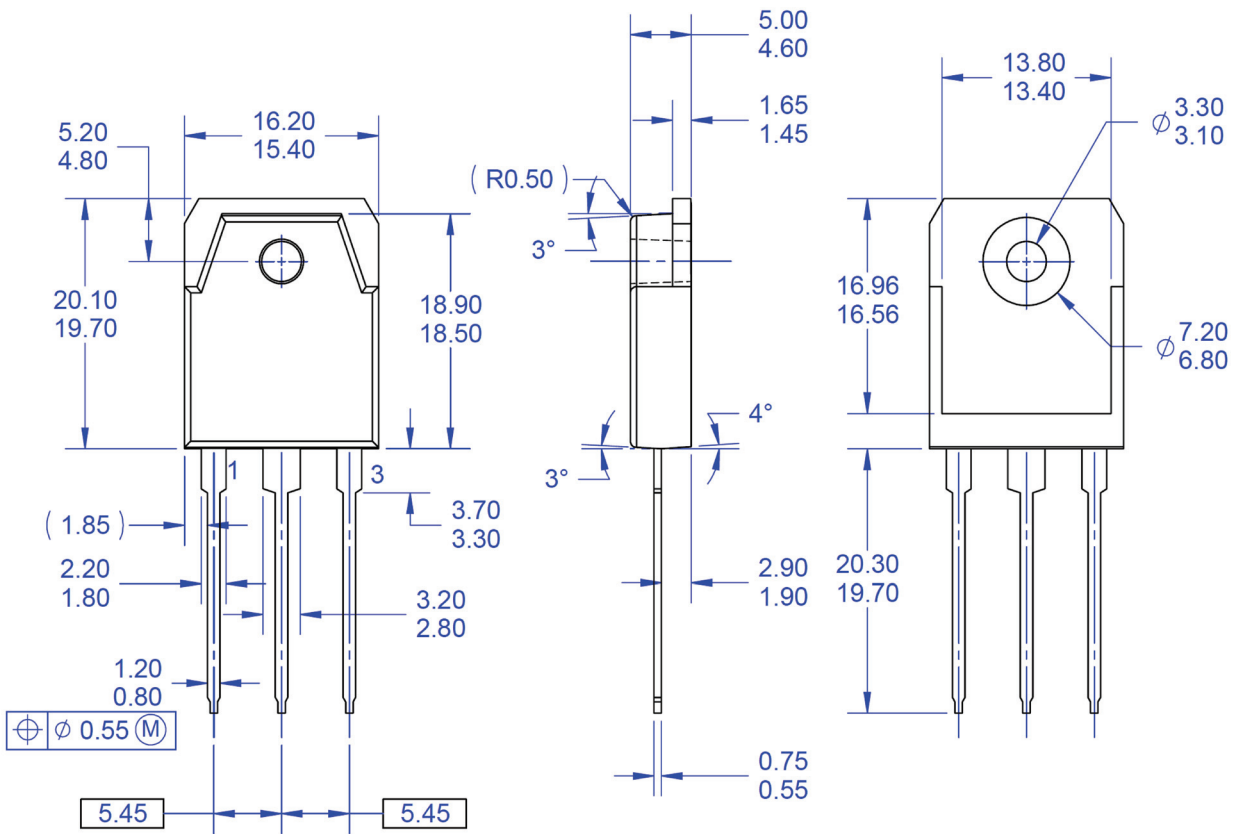


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED

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- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSION AND TOLERANCING PER ASME14.5-2009.
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- E) DRAWING FILE NAME: TO3PN03AREV1.
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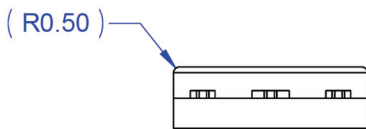


Figure 16. TO3PN, 3-Lead, Plastic, EIAJ SC-65

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